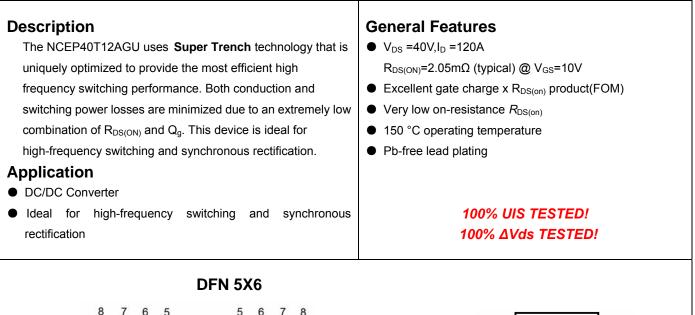
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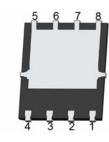


NCE N-Channel Super Trench Power MOSFET

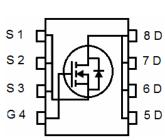




Top View



Bottom View



Schematic Diagram

Package Marking and Ordering Information

i aonago ina n								
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity			
NCEP40T12AGU	NCEP40T12AGU	DFN5X6-8L	-	-	-			

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit			
Drain-Source Voltage	Vds	40	V			
Gate-Source Voltage	Vgs	±20	V			
Drain Current-Continuous (Silicon Limited)	Ι _D	120	А			
Drain Current-Continuous(T _C =100 ℃)	I _D (100℃)	84.8	А			
Pulsed Drain Current (Package Limited)	I _{DM}	400	А			
Maximum Power Dissipation	PD	120	W			
Derating factor		0.96	W/°C			
Single pulse avalanche energy (Note 5)	E _{AS}	480	mJ			
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C			
Thermal Characteristic						
Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	1.04	°C/W			



NCEP40T12AGU

Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· ·					•
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	40		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	2.8	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =60A	-	2.05	2.4	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =60A		56	-	S
Dynamic Characteristics (Note4)	· · ·		-	•		
Input Capacitance	C _{lss}	V _{DS} =20V,V _{GS} =0V,	-	1820	-	PF
Output Capacitance	C _{oss}		-	435	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	34	-	PF
Switching Characteristics (Note 4)	· ·					•
Turn-on Delay Time	t _{d(on)}	V _{DD} =20V,I _D =60A V _{GS} =10V,R _G =1.6Ω	-	7	-	nS
Turn-on Rise Time	tr		-	2.5	-	nS
Turn-Off Delay Time	t _{d(off)}		-	24	-	nS
Turn-Off Fall Time	t _f		-	3.5	-	nS
Total Gate Charge	Qg	V -20V/L -00A	-	24		nC
Gate-Source Charge	Q _{gs}	$V_{DS}=20V, I_{D}=60A,$	-	7		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	3.5		nC
Drain-Source Diode Characteristics			•		•	
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =60A	-		1.2	V
Diode Forward Current	I _S		-	-	120	А
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = I_S	-		21	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-		60	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

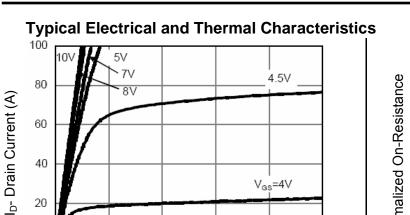
4. Guaranteed by design, not subject to production

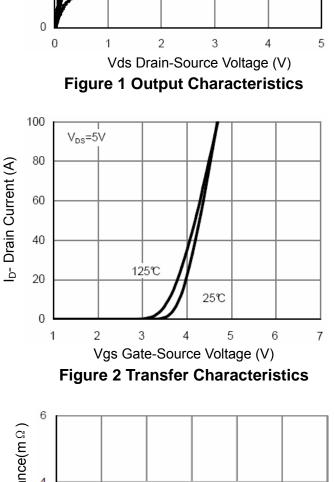
5. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_{DD}=20V,V_G=10V,L=0.5mH,Rg=25 Ω

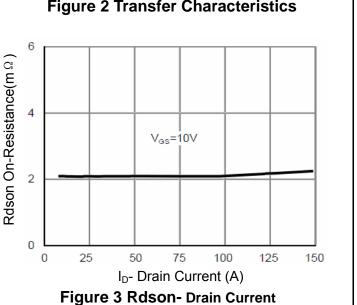


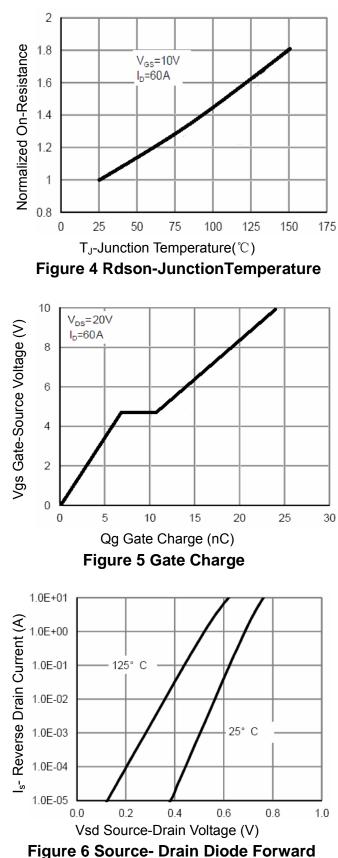
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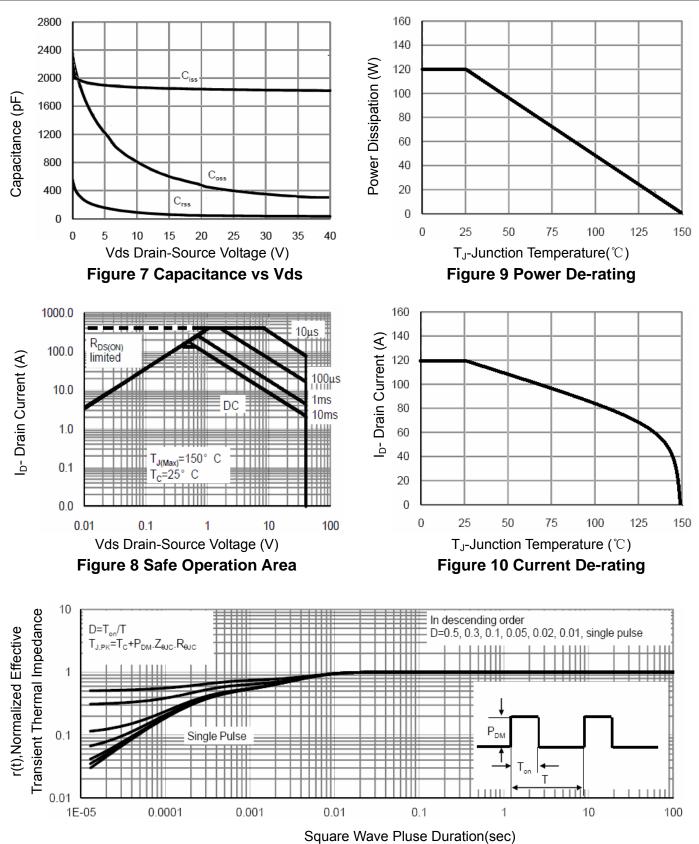


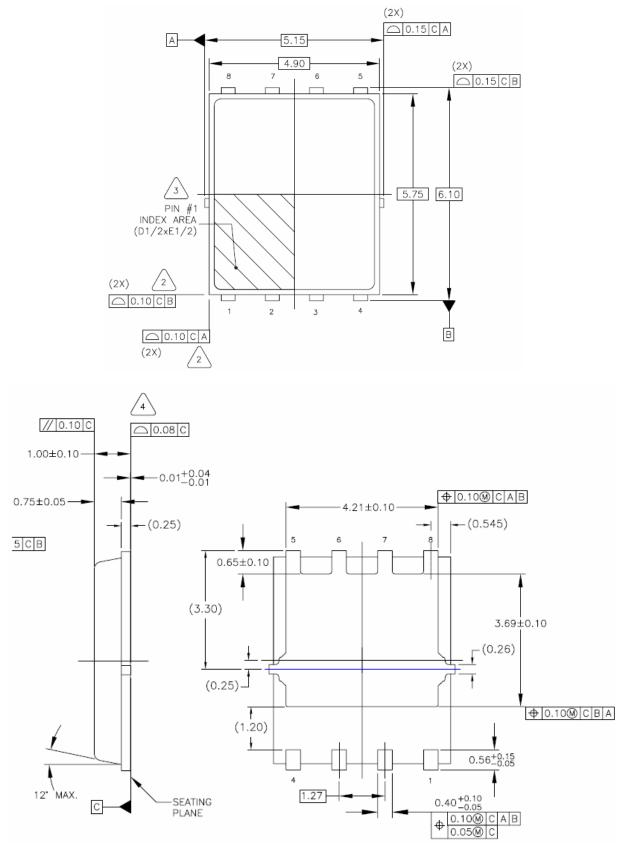
Figure 11 Normalized Maximum Transient Thermal Impedance



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NCEP40T12AGU

DFN5X6-8L Package Information





NCEP40T12AGU

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